

Detecting Spin-Polarized Currents in Ballistic Nanostructures

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(Dated: 6/12/02)

We demonstrate a mesoscopic spin polarizer/analyzer system that allows the spin polarization of current from a quantum point contact in an in-plane magnetic field to be measured. A transverse focusing geometry is used to couple current from an emitter point contact into a collector point contact. At large in-plane fields, with the point contacts biased to transmit only a single spin ($g < e^2/h$), the voltage across the collector depends on the spin polarization of the current incident on it. Spin polarizations of $> 80\%$ are found for both emitter and collector at 300 mK and 7 T in-plane field.

PACS numbers: 72.70.+m, 73.20.Fz, 73.23.-b

The detection of single electron spins has been the aim of extensive experimental efforts for many years. In addition to providing a new tool to investigate the physics of mesoscopic devices, there is hope that the ability to manipulate and measure electron spins in a solid state system may open the way for quantum information processing [1, 2]. However, the long coherence times [3] that make electron spins such a promising system for quantum manipulation result fundamentally from their weak coupling to the environment, and this makes the task of measuring spin difficult.

In this Letter we demonstrate a technique to measure spin by converting the problem into the easier one of measuring charge. At low field and low temperature, a narrow constriction in a 2D electron gas (2DEG), known as a quantum point contact (QPC) [see Fig. 1(a)], transmits through two spin-degenerate channels, producing conductance plateaus at integer multiples of $2e^2/h$. When a large in-plane magnetic field is applied, the degeneracy is lifted and conductance becomes quantized in multiples of $1e^2/h$ [Fig. 1(b)] [4, 5]. While it is widely believed that the e^2/h plateau is associated with spin-polarized transmission, this has not been established experimentally to our knowledge. One key result of this Letter is the demonstration that point contacts do operate as spin emitters and detectors, and therefore allow the detection of spin polarization to be accomplished by simply measuring electrical resistance.

Our experiment is based on a technique known as transverse electron focusing [6], which has been used previously to study phenomena ranging from anisotropy in the band structure of metals [7, 8] and semiconductors [9, 10] to composite fermions in the fractional quantum Hall regime [11]. This device geometry [Fig. 1(a)] allows electrons from a spin-polarizing emitter—in this case a QPC—to be coupled into a second QPC serving as a spin-sensitive collector. A magnetic field, B_z , applied perpendicular to the 2DEG plane, bends and focuses ballistic electron trajectories from the emitter to the collector, resulting in peaks in the base-collector voltage [Figs. 1(c) and 1(d)] whenever the spacing between point

contacts is an integer multiple of the cyclotron diameter, $2m v_F / eB_z$, where m is the effective electron mass and v_F the Fermi velocity.

The coupling efficiency between emitter and collector can be quite high in clean 2DEG materials, allowing the two QPCs to be separated by several microns. This separation is useful for investigating spin physics in mesoscopic structures because it allows spin measurements to be decoupled from the device under test, simplifying the interpretation of results. A further advantage of a focusing geometry is that only ballistic trajectories contribute to the signal, so spin detection occurs very quickly (< 10 ps) after the polarized electrons are emitted, leaving little time for spin relaxation.

In the present experiment, the focusing signal is measured as a voltage between collector and base regions, with fixed current applied between emitter and base [Fig. 1(a)]. With the collector configured as a voltage probe, current injected ballistically into the collector region at the focusing condition must flow back into the base region, giving rise to a voltage $V_c = I_c/g_c$ between collector and base, where I_c is the current injected into the collector and g_c is the conductance of the collector point contact. For this experiment both point contacts are kept at or below one channel of conductance; therefore the collector voltage may be written in terms of the transmission of the collector point contact, T_c (< 1), as $V_c = (2e^2/h)^{-1} I_c = T_c$.

To analyze how spin polarization affects the base-collector voltage, we assume $I_c / I_e T_c$, where I_e is the emitter current, and the constant of proportionality does not depend on the transmissions of either of the point contacts. In the absence of spin effects, one then expects V_c to be independent of g_c . Because I_e is fixed, V_c would also be independent of the emitter conductance, g_e .

Taking into account different transmissions for the two spin channels, however, one expects the voltage on the collector to double if both emitter and collector pass the same spin, or drop to zero if the two pass opposite spins. This conclusion assumes that a spin polarized current injected into the collector region will lose all polarization

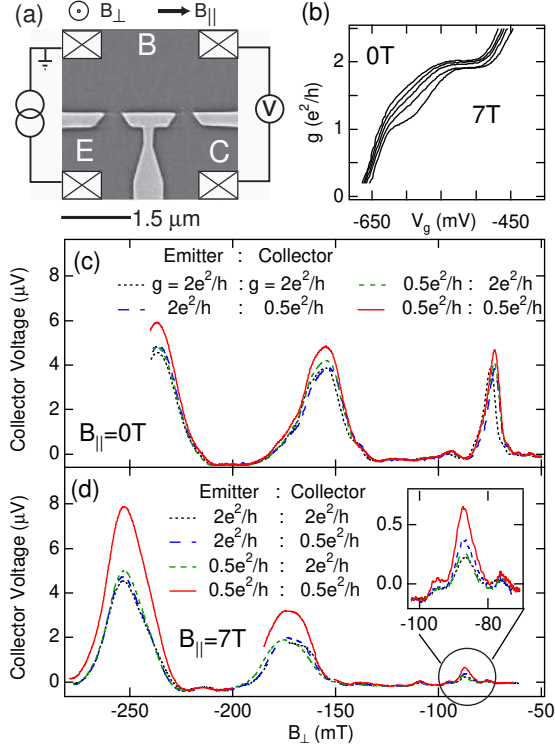


FIG. 1: (a) SEM micrograph of a device similar to the one measured in this experiment, two quantum point contacts in a transverse focusing geometry with perpendicular (B_{\perp}) and in-plane (B_{\parallel}) magnetic fields oriented as shown. With a fixed current applied between emitter (E) and base (B), the voltage between base and collector (C) showed focusing peaks as a function of B_{\perp} . (b) At $T = 300$ mK, both point contacts showed conductance quantized in units of $2e^2/h$ at $B_{\perp} = 0$, and in units of e^2/h at large B_{\perp} . (c) At $B_{\parallel} = 0$, the collector voltage was nearly independent of the conductances of the two point contacts. (d) At $B_{\parallel} = 7$ T the focusing peaks were enhanced only when both emitter and collector were set to $g = 0.5e^2/h$. The enhancement demonstrates that both emitter and detector are spin selective, by Eq. (1).

before flowing out again. Under these conditions, the collector voltage generally depends on the polarization of the emitter current $P_e = (I_{\uparrow} - I_{\downarrow})/(I_{\uparrow} + I_{\downarrow})$ and the spin selectivity of the collector $P_c = (T_{\uparrow} - T_{\downarrow})/(T_{\uparrow} + T_{\downarrow})$ in the following simple way [12]:

$$V_c / \frac{h}{2e^2} I_e (1 + P_e P_c): \quad (1)$$

Note from Eq. 1 that collinear and complete spin polarization ($P_e = 1$) and spin selectivity ($P_c = 1$) gives a collector voltage twice as large as when either emitter or collector is not spin polarized.

The focusing device was fabricated on a high-mobility two-dimensional electron gas (2DEG) formed at the interface of a GaAs/Al_{0.36}Ga_{0.64}As heterostructure, defined using Cr/Au surface depletion gates patterned by electron-beam lithography, and contacted with nonmag-

netic (PtAuGe) ohmic contacts. The 2DEG was 68 nm from the Si-delta-doped layer ($n_{Si} = 2.5 \times 10^{12} \text{ cm}^{-2}$) and 102 nm below the wafer surface. Mobility of the unpatterned 2DEG was $5.5 \times 10^6 \text{ cm}^2/\text{Vs}$ in the dark, limited mostly by remote impurity scattering in the relatively shallow structure, with an estimated background impurity level $< 5 \times 10^{13} \text{ cm}^{-3}$. With an electron density of $1.3 \times 10^{11} \text{ cm}^{-2}$, the transport mean free path was 45 nm , much greater than the distance (1.5 nm) between emitter and collector point contacts. The Fermi velocity associated with this density is $v_F = 2 \times 10^7 \text{ cm/s}$, consistent with the observed 80 mT spacing between focusing peaks.

Measurements were performed in a ^3He cryostat with a base temperature of 300 mK. A conventional superconducting solenoid was used to generate in-plane fields, B_{\parallel} , and a smaller superconducting coil wound on the refrigerator vacuum can allowed fine control of the perpendicular field, B_{\perp} [13]. B_{\parallel} was oriented along the axis between the two point contacts, as shown in Fig. 1 (a).

Independent ac current biases of 1 nA were applied between base and emitter (17 Hz), and base and collector (43 Hz), allowing simultaneous lock-in measurement of the emitter conductance (base-emitter voltage at 17 Hz), collector conductance (base-collector voltage at 43 Hz), and the focusing signal (base-collector voltage at 17 Hz). The base-collector current bias was found to have no effect on the focusing signal. Additionally, the focusing signal was found to be linear in base-emitter current for the small currents used in this measurement.

Measurements were taken over several thermal cycles of the device. While details of focusing peak shapes and point contact conductance traces changed somewhat upon thermal cycling, their qualitative behavior did not change. Although all of the data presented in this paper comes from a single device, the results were confirmed in a similar device on the same heterostructure.

Spin polarization and spin selectivity of the point contacts were detected by comparing the focusing signal (the collector voltage at the top of a focusing peak) for various conductances of the emitter and collector point contacts. At $B_{\parallel} = 0$, where no static spin polarization is expected, the focusing signal was found to be nearly independent of the conductances of both emitter and collector point contacts, as shown in Fig. 1 (c). In contrast, at $B_{\parallel} = 7$ T, the focusing signal observed when both the emitter and collector point contacts were set well below $2e^2/h$ was larger by a factor of ~ 2 compared to the signal when either emitter or collector was set to $2e^2/h$, as seen in Fig. 1 (d). A factor-of-two enhancement is consistent with Eq. (1) for fully spin polarized emission and aligned, fully spin-selective detection.

To normalize for overall variations in transmission through the bulk from the emitter to the collector (for instance upon thermal cycling), the focusing signal at any emitter or collector setting can be normalized by the value when both the emitter and collector are set to $2e^2/h$. We denote the point contact settings as ($x : y$)

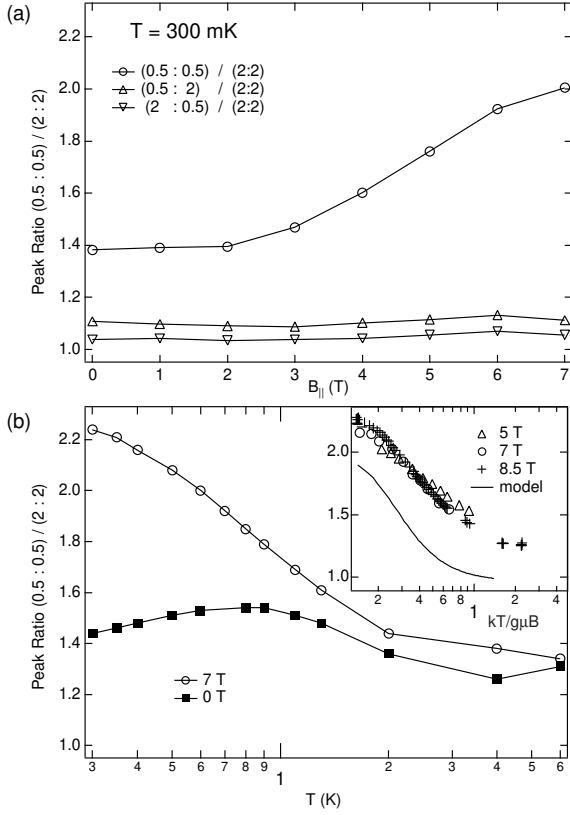


FIG. 2: (a) The height of the third focusing peak as a function of B_k for different conductances of the point contacts ($x : y$), where x is the emitter conductance and y is the collector conductance (in units of e^2/h), all normalized by the $(2 : 2)$ focusing peak height. According to Eq. (1), a factor of two in the ratio indicates fully spin polarized emission and detection. (b) Temperature dependence of the ratio of focusing signals $(0.5 : 0.5) = (2 : 2)$ for $B_k = 7$ T and 0 T. (a) and (b) are from different cooldowns. Inset: Ratio $(0.5 : 0.5) = (2 : 2)$ for $B_k = 5, 7$; and 8.5 T plotted as a function of $kT = g B_k$. The solid curve is the prediction of a simple model (see text) that accounts for only thermal broadening in the leads.

where x is the conductance of the emitter and y is the conductance of the collector, both in units of e^2/h . For instance, $(2 : 2)$ indicates both emitter and collector set to $2e^2/h$ (expected to be unpolarized in any field), while $(0.5 : 0.5)$ indicates both point contacts set to $0.5e^2/h$ (expected to be polarized in a sizable in-plane field). Ratios are then denoted $(x : y) = (2 : 2)$.

Figures 2 and 3 show the focusing signal ratios for the third focusing peak ($B_k = 230 - 250$ mT), chosen because its height and structure in the $(2 : 2)$ condition were less sensitive to B_k and small variations in point contact tuning compared to the first and second peaks. However, all peaks showed qualitatively similar behavior.

Figure 2 (a) shows that only the ratio $(0.5 : 0.5) = (2 : 2)$ grows with B_k , reaching a value 2 at 7 T, while the other ratios, $(2 : 0.5) = (2 : 2)$ and $(0.5 : 2) = (2 : 2)$, are es-

entially independent of in-plane field, as expected from Eq. (1) if no spin selectivity exists when the conductance is $2e^2/h$. At $B_k = 0$, we find $(0.5 : 0.5) = (2 : 2) = 1.4$, rather than the expected 1.0, for this particular cooldown. As discussed below, these ratios fluctuate somewhat between thermal cycles.

Temperature dependences of the $(0.5 : 0.5) = (2 : 2)$ ratio are shown in Fig. 2 (b) for a different cooldown. At $B_k = 7$ T, the ratio $(0.5 : 0.5) = (2 : 2)$ decreases from 2.2 at $T = 300$ mK to the zero-field value of 1.4 above 2 K. Note that 2 K is roughly the temperature at which $g B_k = kT$, using the GaAs g -factor $g = 0.44$. At $B_k = 0$, the ratio $(0.5 : 0.5) = (2 : 2)$ remains near 1.4, with only a weak temperature dependence up to 6 K.

The inset of Fig. 2 (b) shows that focusing data at different values of B_k scale to a single curve when plotted as a function of $kT = g B_k$, suggesting that both spin-polarized emission and spin-selective detection arise from an energy splitting that is linear in B_k . A simple model that accounts roughly for the observed scaling of the focusing signal assumes that the point contact transmission, $T(E)$, is 0 for $E < E_0$, and 1 for $E > E_0$, where E is the electron kinetic energy and E_0 is a gate-voltage-dependent threshold. Spin selectivity then results from the Zeeman splitting of the two spin sub-bands, and is reduced by thermal broadening. Except for a vertical offset of 0.4, this simple model agrees reasonably well with the data [Fig. 2 (b), inset].

Fig. 3 (a) shows the evolution of spin selectivity in the collector point contact as a function of its conductance. At $B_k = 6$ T, with the emitter point contact set to $0.5e^2/h$, the collector point contact is swept from $2e^2/h$ to 0. The focusing signal increases as the collector point contact conductance is reduced below $2e^2/h$, saturating as the collector conductance goes below the e^2/h spin-split plateau. The polarization saturates completely only well into the tunneling regime, below $0.5e^2/h$. Similar to the effect seen in Fig. 2 (b), spin selectivity decreases with increasing temperature, approaching the zero field curve at 1.3 K.

Fig. 3 (b) shows the same measurement taken at $B_k = 0$. The focusing peak rises slightly when both point contacts are set below one spin degenerate channel. Unlike at high field, however, the increase of the focusing signal is very gradual as the point contact is pinched off. In addition, temperature has only a weak effect.

As mentioned above, both the low and high field ratios $(0.5 : 0.5) = (2 : 2)$ were measured to be larger than their ideal theoretical values of 1 and 2 respectively. Sampled over multiple thermal cycles, several gate voltage settings (shifting the point contact centers by 100 nm), and different focusing peaks, the ratio at $B_k = 0$ varied between 1.0 and 1.6, with an average value of 1.25 and a standard deviation ≈ 0.2 . The average value of the ratio at $B_k = 7$ T was 2.1, with ≈ 0.1 .

Both point contacts display a modest amount of zero-field 0.7 structure [14, 15], as seen in Figs. 1 (b) and 3 (b). Although a static spin polarization associated with 0.7

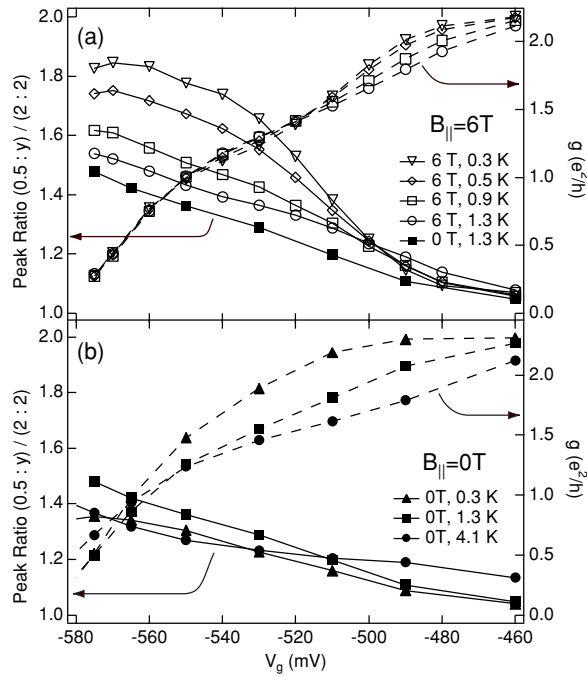


FIG. 3: (a) Focusing signal ratio $(0.5:y)=(2:2)$ and collector conductance g at $B_k = 6$ T as a function of the voltage applied to one of the collector gates, with the emitter fixed at $g = 0.5e^2/h$. This shows the onset of spin selectivity as the collector point contact is brought into the tunneling regime, $g < 2e^2/h$. (b) The same data taken at $B_k = 0$, showing little temperature dependence up to 4 K. A mild 0.7 structure in the conductance becomes more prominent at 1.3 K.

structure would be consistent with our larger-than-one ratio $(0.5:0.5)=(2:2)$ at zero field, this does not explain the enhanced ratio found both at zero field and high field. Rather, we believe the enhancement is due to a slight increase in the efficiency of focusing for $(T_c/T_e) < 1$. For example, more of the emitted current may be focused

into the collector as the point contacts are pinched off, causing deviations from the assumption $I_c / I_e T_c$. This explanation is also consistent with the weak temperature dependence of the zero-field ratio up to 4 K, which would not occur if the enhancement were due to a static polarization at zero field.

An unexplained feature of our data is the relative suppression of the lower-index focusing peaks, particularly the first peak, in a large in-plane field, as seen in Figs. 1(c) and 1(d). This effect was observed over multiple thermal cycles and for all point contact positions. The effect is not readily explained as a field-dependent change in the scattering rate, as neither the bulk mobility, nor the width of the focusing peak is affected. Also, the effect is not obviously related to spin, as it occurred for both polarized and unpolarized point contacts.

In conclusion, we have developed a new method for creating and remotely detecting spin currents using quantum point contacts. The technique has allowed a first demonstration of what was widely expected, namely that a point contact in an in-plane field can act as a spin-polarized emitter and a spin-sensitive detector. From our perspective, however, this result also has a larger significance: it is the first demonstration of a wholly new technique to measure spin-current from a mesoscopic device using a remote electrical spin detector. In future work, this technique can be applied to more subtle mesoscopic spin systems such as measuring spin currents from open or Coulomb-blockaded quantum dots, or directly measuring spin precession due to a spin-orbit interaction.

We acknowledge valuable discussions with H. Bruus, S. Cronenwett, A. Johnson, and H. Lynch. This work was supported in part by ARO-MURI (DAAD 19-99-1-0215) and DARPA-SpinS (DAAD 19-01-1-0659). JAF acknowledges partial support from the Stanford Graduate Fellowship; RMP acknowledges support as an ARO Graduate Research Fellow.

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